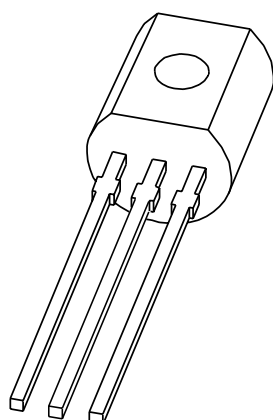


DATA SHEET



BC618 NPN Darlington transistor

Product specification
Supersedes data of 2003 Oct 16

2004 Nov 05

NPN Darlington transistor

BC618

FEATURES

- Low current (max. 500 mA)
- Low voltage (max. 55 V)
- High DC current gain.

APPLICATIONS

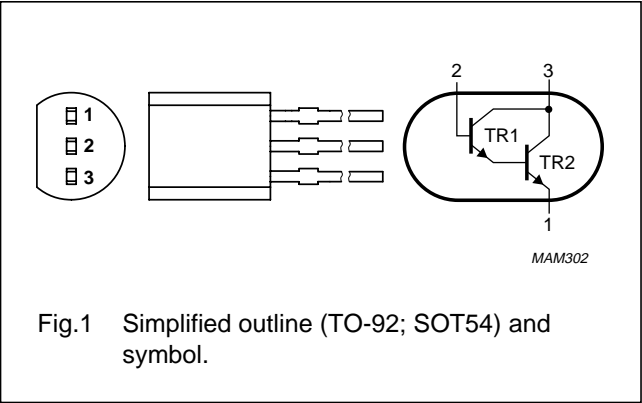
- General purpose low frequency
- Relay drivers.

DESCRIPTION

NPN Darlington transistor in a TO-92; SOT54 plastic package.

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	collector



ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
BC618	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54

NPN Darlington transistor

BC618

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	80	V
V_{CES}	collector-emitter voltage	$V_{BE} = 0$ V	–	55	V
V_{EBO}	emitter-base voltage	open collector	–	12	V
I_C	collector current (DC)		–	500	mA
I_{CM}	peak collector current		–	800	mA
I_B	base current (DC)		–	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	625	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	note 1	200	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

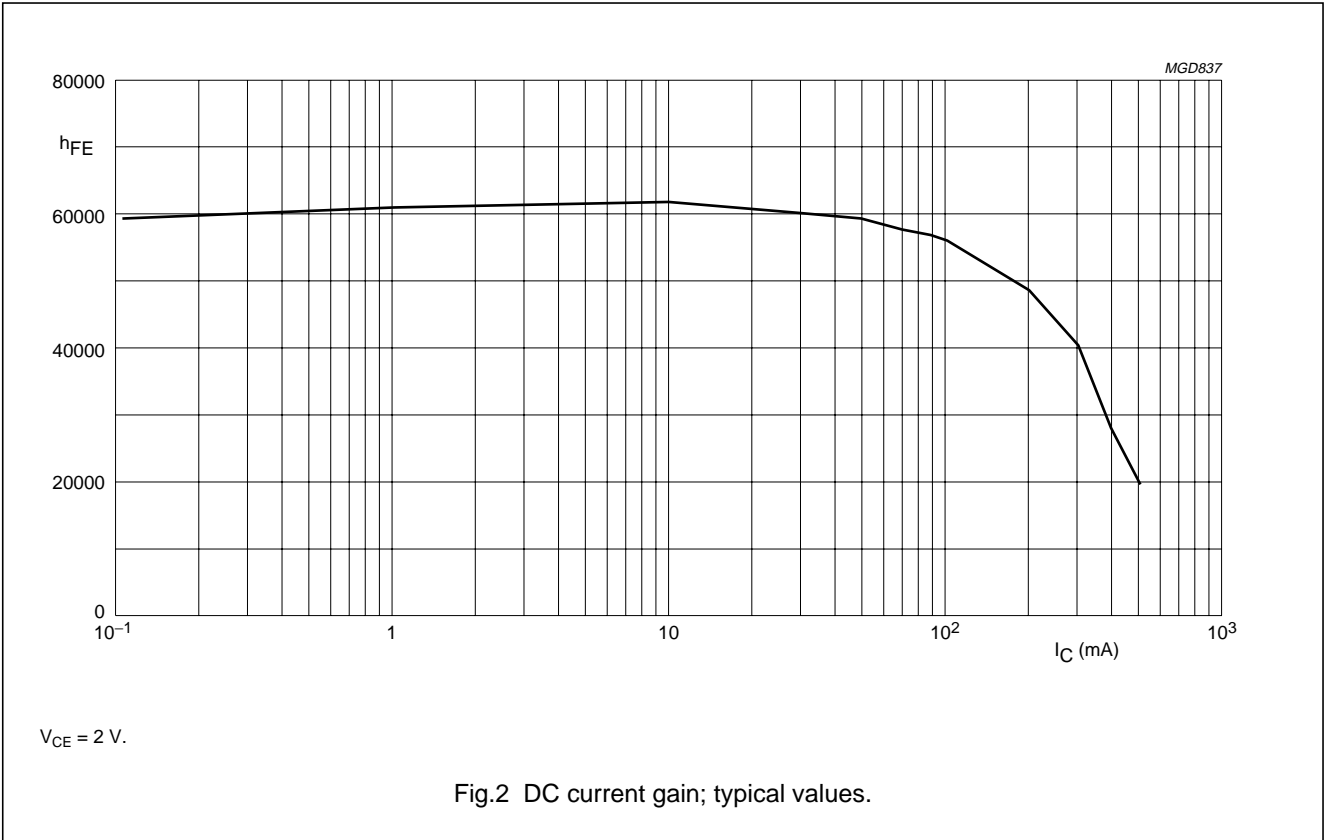
NPN Darlington transistor

BC618

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 60 V; I _E = 0 A	–	–	50	nA
I _{CES}	collector-emitter cut-off current	V _{BE} = 0 V; V _{CE} = 60 V	–	–	50	µA
I _{EBO}	emitter-base cut-off current	V _{EB} = 10 V; I _C = 0 A	–	–	50	nA
h _{FE}	DC current gain	V _{CE} = 5 V; see Fig.2 I _C = 1 mA I _C = 10 mA I _C = 200 mA	2000 4000 10000	– – –	– – 70000	
V _{CEsat}	collector-emitter saturation voltage	I _C = 200 mA; I _B = 0.2 mA	–	–	1.1	V
V _{BEsat}	base-emitter saturation voltage	I _C = 200 mA; I _B = 0.2 mA	–	–	1.6	V
C _c	collector capacitance	V _{CB} = 30 V; I _E = 0 A	–	3.5	–	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 500 mA; f = 100 MHz	155	–	–	MHz



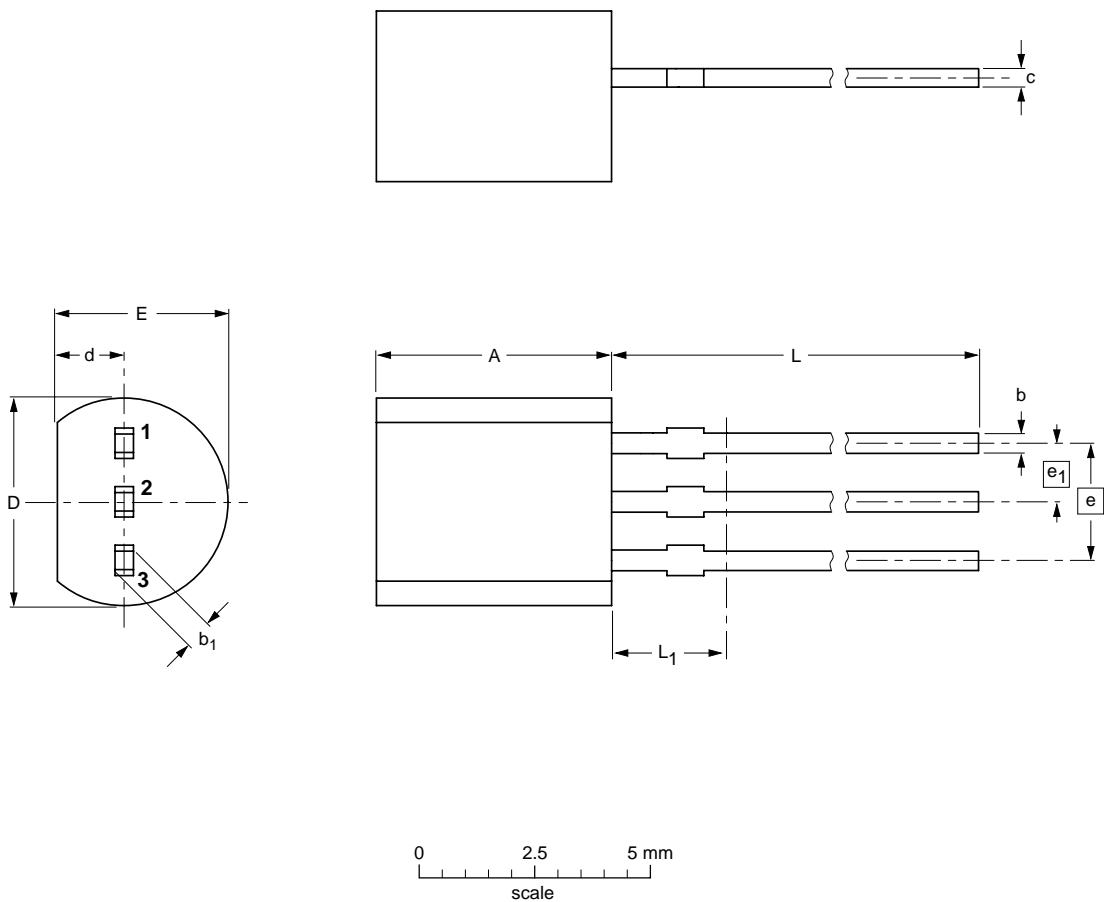
NPN Darlington transistor

BC618

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54




DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	c	D	d	E	e	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT54		TO-92	SC-43A			-97-02-28 04-06-28

NPN Darlington transistor

BC618

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

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3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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SCA76

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